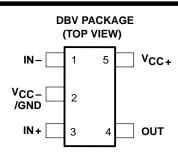
TLV1391, TLV1391Y SINGLE DIFFERENTIAL COMPARATORS

SLCS128A - APRIL 1996 - REVISED APRIL 1996

Low-Voltage and Single-Supply Operation
 V_{CC} = 2 V to 7 V

- Common-Mode Voltage Range Includes Ground
- Fast Response Time 0.7 μs Typ
- Low Supply Current
 80 μA Typ and 150 μA Max
- Fully Specified at 3-V and 5-V Supply Voltages
- Available in SOT-23 (DBV) Packaging



description

The TLV1391 is a differential comparator built using a Texas Instruments low-voltage, high-speed bipolar process. These devices have been specifically developed for low-voltage, single-supply applications. Their enhanced performance makes them excellent replacements for the LM393 in the improved 3-V and 5-V system designs of today.

The TLV1391, with its typical supply current of only 80 μ A, is ideal for low-power systems. Response time has also been improved to 0.7 μ s.

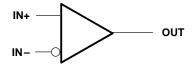
Package availability for this device includes the very small SOT-23 package to reduce board space requirements.

AVAILABLE OPTIONS

т.	PACKAGED DEVICES	SYMBOL	CHIP FORM
TA	SOT-23 (DBV)	STWIBOL	(Y)
0°C to 70°C	TLV1391CDBV	VABC	TLV1391Y
-40°C to 85°C	TLV1391IDBV	VABI	

[†] The DBV package is only available taped and reeled. Chip forms are specified for operation at 25°C only.

symbol (each comparator)

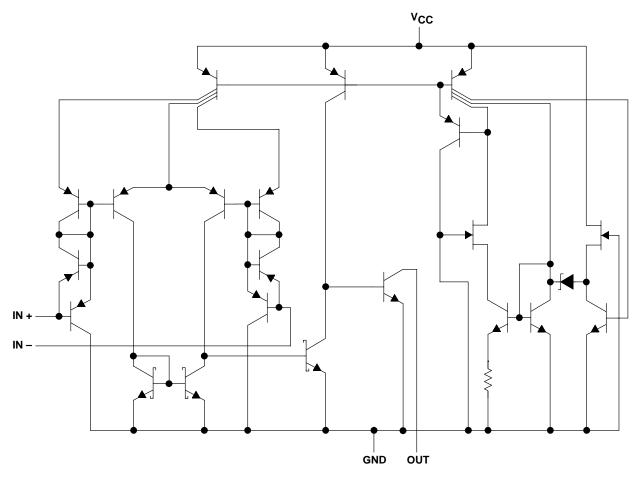




Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



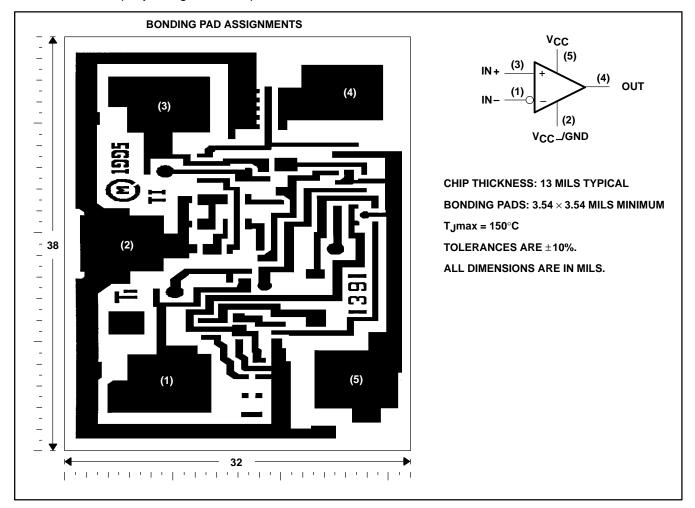
TLV1391, TLV1391Y equivalent schematic



COMPONENT COUNT							
Transistors	26						
Resistors	1						
Diodes	4						
Epi-FET	1						

TLV1391Y chip information

This chip, when properly assembled, displays characteristics similar to the TLV1391. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.



TLV1391, TLV1391Y SINGLE DIFFERENTIAL COMPARATORS

SLCS128A - APRIL 1996 - REVISED APRIL 1996

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	
Differential input voltage, V _{ID} (see Note 2)	
Input voltage, V _I (any input)	0.3 V to V _{CC}
Output voltage, V _O	7 V
Output current, IO (each output)	20 mA
Duration of short-circuit current to GND (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A : C suffix	0°C to 70°C
I suffix	40°C to 85°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the network GND.

- 2. Differential voltages are at the noninverting input with respect to the inverting input.
- 3. Short circuits from the outputs to V_{CC} can cause excessive heating and eventual destruction of the chip.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
DBV	150 mW	1.2 mW/° C	96 mW	78 mW

recommended operating conditions

	C SU	FFIX	I SUF	LINUT	
	MIN MA	MAX	MIN	MAX	UNIT
Supply voltage, V _{CC}	2	7	2	7	V
Operating free-air temperature, T _A	0	70	-40	85	°C



SLCS128A - APRIL 1996 - REVISED APRIL 1996

electrical characteristics, $V_{CC} = 3 V$

DADAMETED		TEST CONDITIONS	T _A †		ΓLV1391C			
	PARAMETER	PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT	
\/.a	Input offeet voltege	Vo - 1.4.V. Vo - Vianmin	25°C		1.5	5	mV	
VIO	Input offset voltage	$V_O = 1.4 \text{ V}, V_O = V_{ICR} \text{min}$	Full range			9	IIIV	
			25°C	0 to	0 to			
VICR	Common-mode input voltage range		25 0	V _{CC} – 1.5	V _{CC} -1.2		V	
VICR	Common-mode input voltage range		Full range	0 to			V	
			1 dil range	V _{CC} -2				
VOL	Low-level output voltage	$V_{ID} = -1 \text{ V}, I_{OL} = 500 \mu\text{A}$	Full range		120	300	mV	
1	Input offset current	V- 4.4.V	25°C		5	50	~^	
lio		nput offset current V _O = 1.4 V				150	nA	
L.		lanut hian sumant	V- 44V	25°C		-40	-250	A
lΒ	Input bias current	ut bias current V _O = 1.4 V				-400	nA	
1	Lligh lovel cutnut current	V _{ID} = 1 V, V _{OH} = 3 V	25°C		0.1		~^	
ЮН	High-level output current $V_{ID} = 1 \text{ V},$	V _{ID} = 1 V, V _{OH} = 5 V	Full range			100	nA	
loL	Low-level output current	$V_{ID} = -1 \text{ V}, V_{OL} = 1.5 \text{ V}$	25°C	500			μΑ	
1	High level comply compat	Ma Mari	25°C		80	125		
ICC(H)	H) High-level supply current	VO = VOH	Full range			150		
la a n :	Low lovel cumply cumpent	Va. Va.	25°C		80	125	μΑ	
ICC(L)	Low-level supply current	AO = AOF	Full range			150		

[†] Full range is 0°C to 70°C.

switching characteristics, V_{CC} = 3 V, C_L = 15 pF † , T_A = 25 $^{\circ}$ C

PARAMETER	TEST CONDITIONS	TI	_V13910		UNIT
FARAMETER	TEST CONDITIONS		TYP	MAX	UNIT
Response time	100-mV input step with 5-mV overdrive, $R_L = 5.1 \text{ k}\Omega$		0.7		μs

[†]C_L includes the probe and jig capacitance.

TLV1391, TLV1391Y SINGLE DIFFERENTIAL COMPARATORS

SLCS128A – APRIL 1996 – REVISED APRIL 1996

electrical characteristics, $V_{CC} = 5 V$

PARAMETER		TEOT 00	NOTIONS	- +	T	LV1391C		
	PARAMETER		NDITIONS	T _A †	MIN	TYP	MAX	UNIT
V	lanut effect voltage	V= 44V \	/ \/in	25°C		1.5	5	m)/
VIO	Input offset voltage	VO = 1.4 V, V	VIC = VICRmin	Full range			9	mV
				25°C	0 to	0 to		
Vion	Common-mode input voltage range			25 0	V _{CC} – 1.5	V _{CC} -1.2		V
VICR	Common-mode input voltage range			Full range	0 to			V
				1 ull range	V _{CC} -2			
VOL	Low-level output voltage	$V_{ID} = -1 V$, I	OL = 500 μA	Full range		120	300	mV
1	Input offset current	V _O = 1.4 V		25°C		5	50	A
lo lo		νO = 1.4 ν		Full range			150	nA
	land him admin	V 44V		25°C		-40	-250	A
ΙΒ	Input bias current	V _O = 1.4 V		Full range			-400	nA
1	High lovel output ourrent	V _{ID} = 1 V,	√ _{OH} = 3 V	25°C		0.1		- A
ЮН	High-level output current	V _{ID} = 1 V,	√ _{OH} = 5 V	Full range			100	nA
loL	Low-level output current	$V_{ID} = -1 V$, \	√ _{OL} = 1.5 V	25°C	600			μΑ
1	High lovel cumply current	Va Va		25°C		100	150	
ICC(H)	High-level supply current	AO = AOH	= vOH				175	
1	Low lovel cumply current	Va Va.		25°C		100	150	μΑ
ICC(L)	Low-level supply current	$AO = AO\Gamma$		Full range			175	

[†] Full range is 0°C to 70°C.

switching characteristics, V_{CC} = 5 V, C_L = 15 pF † , T_A = 25 $^{\circ}$ C

PARAMETER	TEST CONDITIONS	TEST CONDITIONS			TLV1391C			
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT		
Response time	100-mV input step with 5-mV overdrive,	$R_L = 5.1 \text{ k}\Omega$		0.65				
Response time	TTL-level input step,	$R_L = 5.1 \text{ k}\Omega$		0.18		μs		

[†]C_L includes the probe and jig capacitance.

SLCS128A - APRIL 1996 - REVISED APRIL 1996

electrical characteristics, $V_{CC} = 3 V$

DADAMETER		TEST CONDITIONS		_ +		TLV1391I			
	PARAMETER	TEST CONDITIONS	`	T _A †	MIN	TYP	MAX	UNIT	
\/	land offert valte as	V- 4.4.V. V:- V:		25°C		1.5	5	\/	
VIO	Input offset voltage	$V_O = 1.4 \text{ V}, V_{IC} = V_{ICF}$	Sunin	Full range			9	mV	
				25°C	0 to	0 to			
\/.op	Common-mode input voltage range			25 0	V _{CC} – 1.5	V _{CC} -1.2		V	
VICR	Common-mode input voltage range			Full range	0 to			V	
				ruii rariye	V _{CC} -2				
VOL	Low-level output voltage	$V_{ID} = -1 \text{ V}, OL = 500 \mu$	ιA	Full range		120	300	mV	
1	Input offset current	Input offset current	V- 4.4.V		25°C		5	50	A
ΙO		V _O = 1.4 V	Γ	Full range			150	nA	
	Input bias current	V 4.4V		25°C		-40	-250	- A	
lΒ		input bias current	V _O = 1.4 V	Γ	Full range			-400	nA
1	High lovel cutout current	V _{ID} = 1 V, V _{OH} = 3 V		25°C		0.1		~^	
ЮН	High-level output current V _{ID} = 1 V, V	$V_{ID} = 1 \text{ V}, V_{OH} = 5 \text{ V}$		Full range			100	nA	
l _{OL}	Low-level output current	$V_{ID} = -1 \text{ V}, V_{OL} = 1.5 \text{ V}$	V	25°C	500			μΑ	
1	High level supply supply	Wa Wass		25°C		80	125		
ICC(H)	High-level supply current	VO = VOH	Ī	Full range			150		
	Level and a second	V V		25°C		80	125	μΑ	
ICC(L)	Low-level supply current	w-level supply current $V_O = V_{OL}$		Full range			150		

[†] Full range is –40°C to 85°C.

switching characteristics, V_{CC} = 3 V, C_L = 15 pF[†], T_A = 25°C

PARAMETER	TEST CONDITIONS	Т	LV1391I		UNIT
FARAWETER	TEST CONDITIONS	MIN	TYP	MAX	
Response time	100-mV input step with 5-mV overdrive, $R_L = 5.1 \text{ k}\Omega$		0.7		μs

[†]C_L includes the probe and jig capacitance.

TLV1391, TLV1391Y SINGLE DIFFERENTIAL COMPARATORS

SLCS128A – APRIL 1996 – REVISED APRIL 1996

electrical characteristics, $V_{CC} = 5 \text{ V}$

PARAMETER		TEST C	ONDITIONS	- +	•	TLV1391I		UNIT
	PARAMETER	TANAMETER TEST CONDITIONS		T _A †	MIN	TYP	MAX	UNII
\/10	Input offset voltage	Vo = 1.4.V	V _{IC} = V _{ICR} min	25°C		1.5	5	mV
VIO	input onset voltage	VO = 1.4 V,	AIC = AICKIIIII	Full range			9	IIIV
				25°C	0 to	0 to		
VICR	Common-mode input voltage range			20 0	V _{CC} – 1.5	V _{CC} –1.2		V
VICK	Common-mode input voitage range			Full range	0 to V _{CC} -2			v
VOL	Low-level output voltage	$V_{ID} = -1 V$,	OL = 500 μA	Full range		120	300	mV
1	Input offset current	V= 1.4.V	'o - 1 4 V			5	50	nA
10		V _O = 1.4 V		Full range			150	ΠA
1	lanut bigg gurrant	V= 1.4.V		25°C		-40	-250	nA
IВ	Input bias current	V _O = 1.4 V		Full range			-400	ΠA
lo	High-level output current	$V_{ID} = 1 V$,	V _{OH} = 3 V	25°C		0.1		nA
ЮН	nigh-level output current	$V_{ID} = 1 V$,	V _{OH} = 5 V	Full range			100	IIA
l _{OL}	Low-level output current	$V_{ID} = -1 V$,	V _{OL} = 1.5 V	25°C	600			μΑ
1	High level comply compant	V- V	\/	25°C		100	150	
ICC(H)	High-level supply current	VO = VOH		Full range			175	
laan)	Low level cumply current	Va - Va		25°C		100	150	μΑ
ICC(L)	Low-level supply current	AO = AOF		Full range			175	

[†] Full range is –40°C to 85°C.

switching characteristics, V_{CC} = 5 V, C_L = 15 pF † , T_A = 25 $^{\circ}$ C

PARAMETER	TEST CONDITIONS		TLV1391I			UNIT	
FARAMETER			MIN	TYP	MAX	UNIT	
Response time	100-mV input step with 5-mV overdrive,	$R_L = 5.1 \text{ k}\Omega$		0.65			
Response time	TTL-level input step,	$R_L = 5.1 \text{ k}\Omega$		0.18		μs	

[†]C_L includes the probe and jig capacitance.



electrical characteristics, V_{CC} = 3 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TLV1391Y			UNIT
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII
V _{IO}	Input offset voltage	$V_O = 1.4 \text{ V}, V_{IC} = V_{ICR} \text{min}$		1.5	5	mV
VICR	Common-mode input voltage range		0 to V _{CC} – 1.5	0 to V _{CC} -1.2		٧
IIO	Input offset current	V _O = 1.4 V		5	50	nA
I _{IB}	Input bias current	V _O = 1.4 V		-40	-250	nA
ІОН	High-level output current	$V_{ID} = 1 \text{ V}, V_{OH} = 3 \text{ V}$		0.1		nA
lOL	Low-level output current	$V_{ID} = -1 \text{ V}, V_{OL} = 1.5 \text{ V}$	500			μΑ
ICC(H)	High-level supply current	VO = VOH		80	125	
ICC(L)	Low-level supply current	$V_O = V_{OL}$		80	125	μΑ

switching characteristics, V_{CC} = 3 V, C_L = 15 pF[†], T_A = 25°C

PARAMETER	TEST CONDITIONS		TLV1391Y		
FARAMETER			TYP	MAX	UNIT
Response time	100-mV input step with 5-mV overdrive, $R_L = 5.1 \text{ k}\Omega$		0.7		μs

 $^{^{\}dagger}\text{C}_{L}$ includes the probe and jig capacitance.

electrical characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TLV1391Y			UNIT
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIO	Input offset voltage	$V_O = 1.4 \text{ V}, V_{IC} = V_{ICR} \text{min}$		1.5	5	mV
VICR	Common-mode input voltage range		0 to V _{CC} – 1.5	0 to V _{CC} -1.2		٧
lιο	Input offset current	V _O = 1.4 V		5	50	nA
I _{IB}	Input bias current	V _O = 1.4 V		-40	-250	nA
loн	High-level output current	$V_{ID} = 1 \text{ V}, V_{OH} = 3 \text{ V}$		0.1		nA
l _{OL}	Low-level output current	$V_{ID} = -1 \text{ V}, V_{OL} = 1.5 \text{ V}$	600			μΑ
I _{CC(H)}	High-level supply current	$V_O = V_{OH}$		100	150	
ICC(L)	Low-level supply current	$V_O = V_{OL}$		100	150	μΑ

switching characteristics, V_{CC} = 5 V, C_L = 15 pF[†], T_A = 25°C

PARAMETER	TEST CONDITIONS TLV1391 MIN TYP		TLV1391Y			UNIT
PARAMETER			TYP	MAX	UNIT	
Response time	100-mV input step with 5-mV overdrive,	$R_L = 5.1 \text{ k}\Omega$		0.65		
Response time	TTL-level input step,	R _L = 5.1 kΩ		0.18		μs

[†]C_L includes the probe and jig capacitance.

TLV1391, TLV1391Y SINGLE DIFFERENTIAL COMPARATORS

SLCS128A – APRIL 1996 – REVISED APRIL 1996

TYPICAL CHARACTERISTICS

Table of Graphs

Input overdrives for TLV1391	vs Low-to-high-level output response time	1, 3	
	vs High-to-low-level output response time	2, 4	

ACC = 3 A

 $T_A = 25^{\circ} C$

TYPICAL CHARACTERISTICS

V I(STEP) – Input Voltage Step – mV

100

0

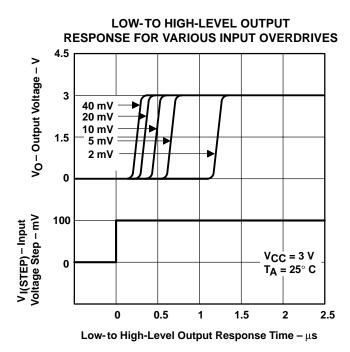


Figure 1

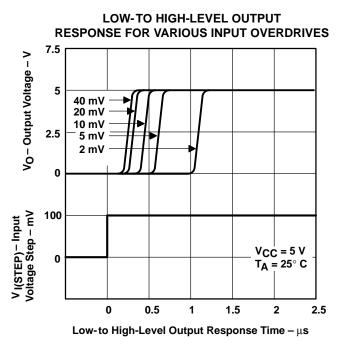


Figure 3

HIGH-TO LOW-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES 4.5 40 mV 20 mV 10 mV 5 mV 2 mV

0 0.2 0.4 0.6 0.8 High-to Low-Level Output Response Time – μs

Figure 2

HIGH-TO LOW-LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

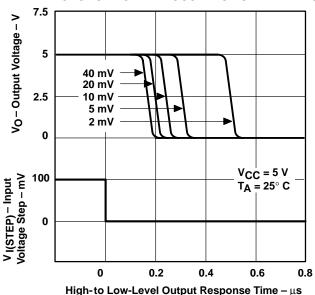


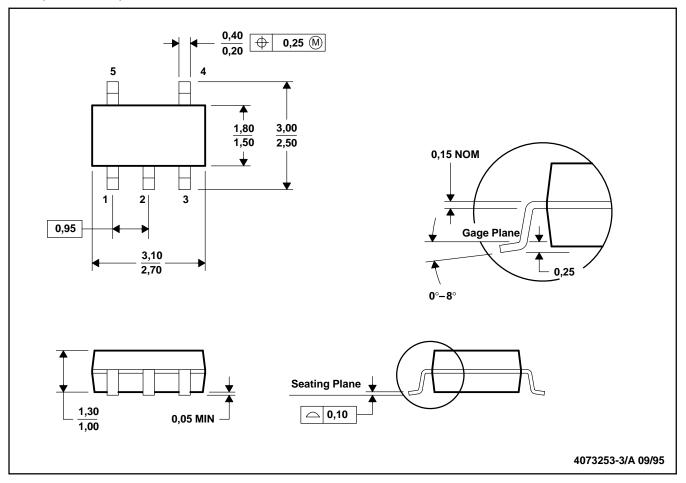
Figure 4

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MECHANICAL DATA

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions include mold flash or protrusion.

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